Onsemi

Industrial Inductive Load Driver

NUD3160, SZNUD3160

This micro-integrated part provides a single component solution to switch inductive loads such as relays, solenoids, and small DC motors without the need of a free-wheeling diode. It accepts logic level inputs, thus allowing it to be driven by a large variety of devices including logic gates, inverters, and microcontrollers.

Features

- Provides Robust Interface between D.C. Relay Coils and Sensitive Logic
- Capable of Driving Relay Coils Rated up to 150 mA at 12 V, 24 V or 48 V
- Replaces 3 or 4 Discrete Components for Lower Cost
- Internal Zener Eliminates Need for Free–Wheeling Diode
- Meets Load Dump and other Automotive Specs
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Automotive and Industrial Environment
- Drives Window, Latch, Door, and Antenna Relays

Benefits

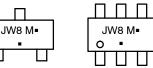
- Reduced PCB Space
- Standardized Driver for Wide Range of Relays
- Simplifies Circuit Design and PCB Layout
- Compliance with Automotive Specifications



SOT-23 **CASE 318** STYLE 21

SC-74 **CASE 318F** STYLE 7





- JW8 = Specific Device Code Μ = Date Code
 - = Pb-Free Package

(Note: Microdot may be in either location)

Μ = Date Code

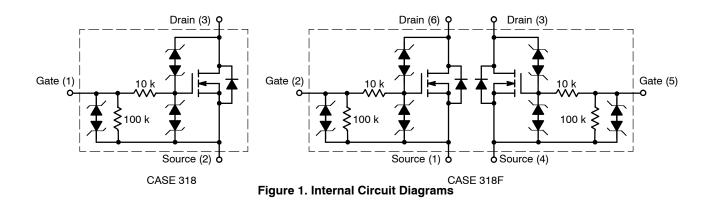
= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NUD3160LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SZNUD3160LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NUD3160DMT1G	SC–74 (Pb–Free)	3000 / Tape & Reel
SZNUD3160DMT1G	SC-74 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



MAXIMUM RATINGS (T_J = 25° C unless otherwise specified)

Symbol	Rating	Value	Unit
V _{DSS}	Drain-to-Source Voltage - Continuous (T _J = 125°C)	60	V
V _{GSS}	Gate-to-Source Voltage – Continuous (T _J = 125°C)	12	V
ID	Drain Current – Continuous ($T_J = 125^{\circ}C$) Minimum copper, double sided board, $T_A = 80^{\circ}C$ SOT-23 SC74 Single device driven SC74 Both devices driven 1 in ² copper, double sided board, $T_A = 25^{\circ}C$ SOT-23 SC74 Single device driven SC74 Both devices driven	158 157 132 ea 272 263 230 ea	mA
EZ	Single Pulse Drain-to-Source Avalanche Energy (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	200	mJ
P _{PK}	Peak Power Dissipation, Drain-to-Source (Notes 1 and 2) (T _J Initial = 85°C)	20	W
E _{LD1}	Load Dump Pulse, Drain-to-Source (Note 3) $R_{SOURCE} = 0.5 \Omega$, T = 300 ms) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	60	V
E _{LD2}	Inductive Switching Transient 1, Drain-to-Source (Waveform: $R_{SOURCE} = 10 \Omega$, T = 2.0 ms) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	100	V
E _{LD3}	Inductive Switching Transient 2, Drain-to-Source (Waveform: $R_{SOURCE} = 4.0 \Omega$, T = 50 µs) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	300	V
Rev-Bat	Reverse Battery, 10 Minutes (Drain-to-Source) (For Relay's Coils/Inductive Loads of 80 Ω or more)	-14	V
Dual-Volt	Dual Voltage Jump Start, 10 Minutes (Drain-to-Source)	28	V
ESD	Human Body Model (HBM) According to EIA/JESD22/A114 Specification	2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Rating	Value	Unit
T _A	Operating Ambient Temperature	-40 to 125	°C
Τ _J	Maximum Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	-65 to 150	°C
PD	Total Power Dissipation (Note 4) SOT-23 Derating above 25°C SOT-23	225 1.8	mW mW/°C
PD	Total Power Dissipation (Note 4) SC-74 Derating above 25°C SC-74	380 3.0	mW mW/°C
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient Minimum Copper SC-74 One Device Powered SC-74 Both Devices Equally Powered	556	°C/W
	300 mm ² Copper SOT-23 SC-74 One Device Powered SC-74 Both Devices Equally Powered	395 420 270	

1. Nonrepetitive current square pulse 1.0 ms duration.

For different square pulse durations, see Figure 12.
Nonrepetitive load dump pulse per Figure 3.
Mounted onto minimum pad board.

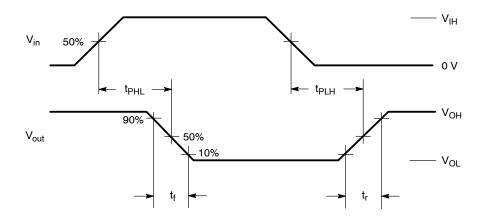
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

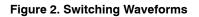
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Drain to Source Sustaining Voltage (I _D = 10 mA)	V _{BRDSS}	61	66	70	V
$ Drain to Source Leakage Current \\ (V_{DS} = 12 V, V_{GS} = 0 V) \\ (V_{DS} = 12 V, V_{GS} = 0 V, T_J = 125^{\circ}C) \\ (V_{DS} = 60 V, V_{GS} = 0 V) \\ (V_{DS} = 60 V, V_{GS} = 0 V, T_J = 125^{\circ}C) \\ \end{array} $	IDSS	- - -	- - - -	0.5 1.0 50 80	μΑ
Gate Body Leakage Current ($V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V}$) ($V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V}, T_J = 125^{\circ}\text{C}$) ($V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V}$) ($V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V}, T_J = 125^{\circ}\text{C}$)	I _{GSS}	- - -	- - -	60 80 90 110	μΑ
ON CHARACTERISTICS					
Gate Threshold Voltage $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA})$ $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA}, T_J = 125^{\circ}\text{C})$	V _{GS(th)}	1.3 1.3	1.8 _	2.0 2.0	V
Drain to Source On-Resistance ($I_D = 150 \text{ mA}, V_{GS} = 3.0 \text{ V}$) ($I_D = 150 \text{ mA}, V_{GS} = 3.0 \text{ V}, T_J = 125^{\circ}\text{C}$) ($I_D = 150 \text{ mA}, V_{GS} = 5.0 \text{ V}$) ($I_D = 150 \text{ mA}, V_{GS} = 5.0 \text{ V}, T_J = 125^{\circ}\text{C}$)	R _{DS(on)}	- - -	- - -	2.4 3.7 1.8 2.9	Ω
Output Continuous Current ($V_{DS} = 0.3 \text{ V}, V_{GS} = 5.0 \text{ V}$) ($V_{DS} = 0.3 \text{ V}, V_{GS} = 5.0 \text{ V}, T_J = 125^{\circ}\text{C}$)	I _{DS(on)}	150 100	200 _		mA
Forward Transconductance $(V_{DS} = 12 \text{ V}, I_D = 150 \text{ mA})$	9fs	-	400	-	mmho
DYNAMIC CHARACTERISTICS	-	-	-	-	
Input Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	C _{iss}	_	30	-	pf
Output Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	C _{oss}	-	14	-	pf
Transfer Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	C _{rss}	_	6.0	-	pf
SWITCHING CHARACTERISTICS	_	_	_	_	
Propagation Delay Times: High to Low Propagation Delay; Figure 2, $(V_{DS} = 12 \text{ V}, V_{GS} = 3.0 \text{ V})$ Low to High Propagation Delay; Figure 2, $(V_{DS} = 12 \text{ V}, V_{GS} = 3.0 \text{ V})$	t _{PHL} t _{PLH}		918 798		ns
High to Low Propagation Delay; Figure 2, (V _{DS} = 12 V, V _{GS} = 5.0 V) Low to High Propagation Delay; Figure 2, (V _{DS} = 12 V, V _{GS} = 5.0 V)	t _{PHL} t _{PLH}	_	331 1160	-	
Transition Times: Fall Time; Figure 2, (V _{DS} = 12 V, V _{GS} = 3.0 V) Rise Time; Figure 2, (V _{DS} = 12 V, V _{GS} = 3.0 V)	t _f tr		2290 618		ns
Fall Time; Figure 2, (V $_{DS}$ = 12 V, V $_{GS}$ = 5.0 V) Rise Time; Figure 2, (V $_{DS}$ = 12 V, V $_{GS}$ = 5.0 V)	t _f t _r		622 600	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL WAVEFORMS

(T_J = 25°C unless otherwise specified)





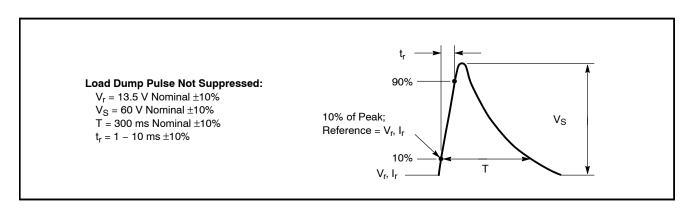
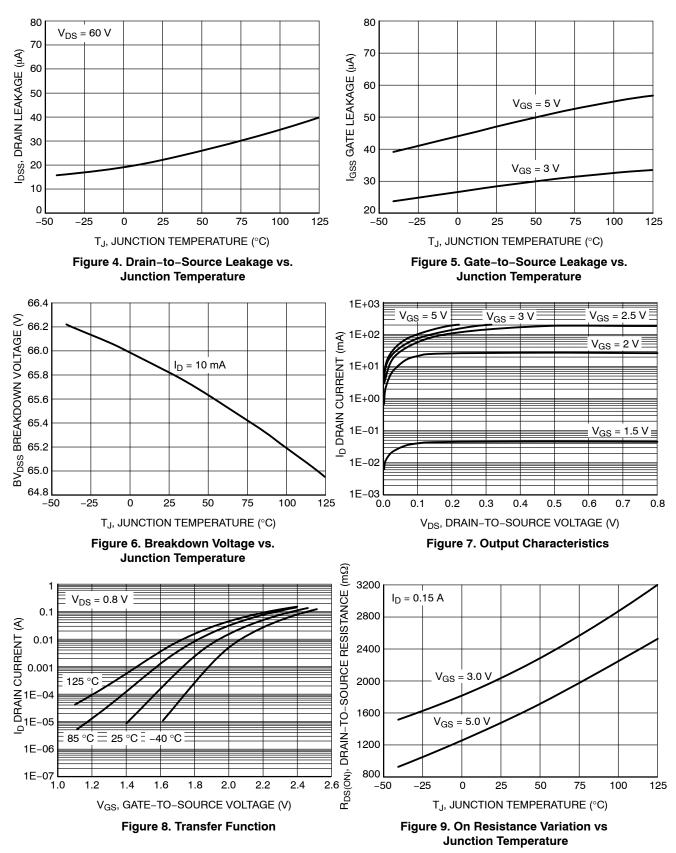


Figure 3. Load Dump Waveform Definition

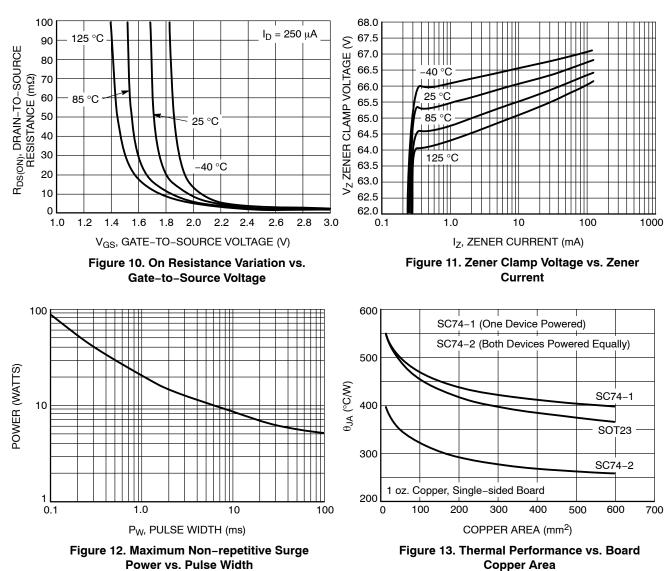
TYPICAL PERFORMANCE CURVES

 $(T_J = 25^{\circ}C \text{ unless otherwise specified})$



TYPICAL PERFORMANCE CURVES

 $(T_J = 25^{\circ}C \text{ unless otherwise specified})$



<u>www.onsemi.com</u> 6

APPLICATIONS INFORMATION

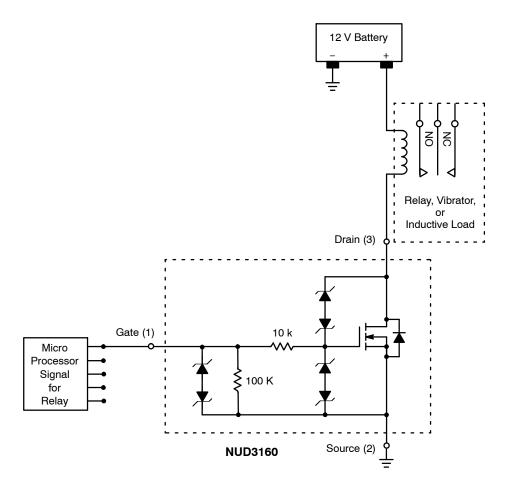


Figure 14. Applications Diagram

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

D

3

TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

DUSem



SCALE 4:1

Α A1SOT-23 (TO-236) **CASE 318 ISSUE AT**

0.25

-L1

DETAIL A

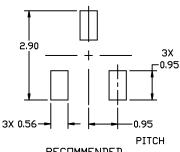
END VIEW

DATE 01 MAR 2023

NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- CONTROLLING DIMENSION: MILLIMETERS 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF THE BASE MATERIAL. З.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4.

	MILLIM	ILLIMETERS INCHES				
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
с	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
Η _E	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10*	0*		10*



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D. *

GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code

М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42226B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	SOT-23 (TO-236)		PAGE 1 OF 2			
the right to make changes without furth purpose, nor does onsemi assume ar	onsemi and ONSEMI. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.					

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

onsemi

SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

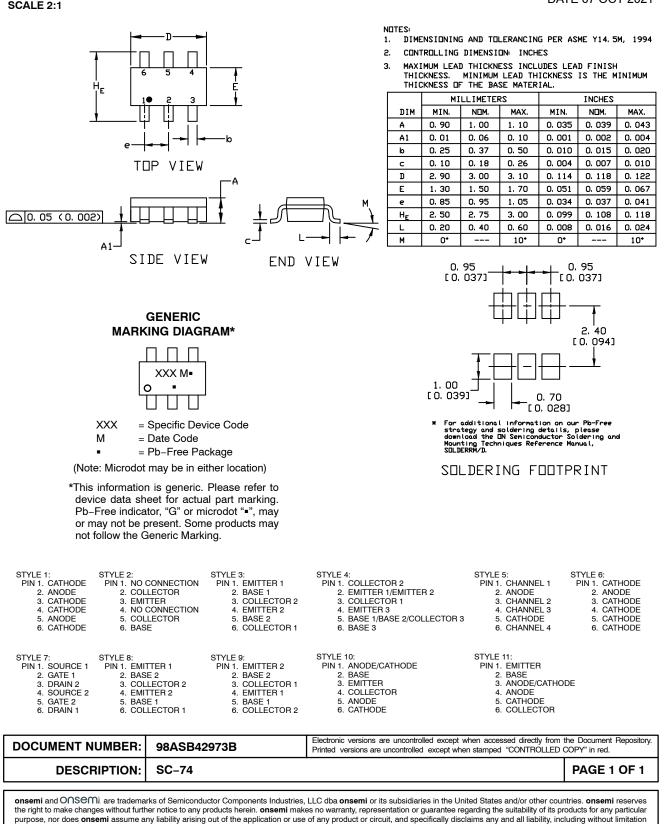
DOCUMENT NUMBER:	98ASB42226B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOT-23 (TO-236)		PAGE 2 OF 2	

onsemi and ONSEMi. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi

SC-74 CASE 318F ISSUE P

DATE 07 OCT 2021



special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative